

T495D477K006ATE125

T495, Tantalum, MnO2 Tantalum, 470 uF, 10%, 6.3 VDC, SMD, MnO2, Molded, Low ESR, 125 mOhms, 7343, Height Max = 3.1mm

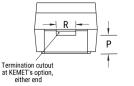
CATHODE (-) END VIEW

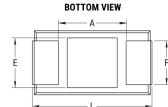


ANODE (+) END VIEW



SIDE VIEW





Click here for the 3D model.

Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	2.8mm +/-0.3mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
А	3.6mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
Р	0.9mm REF
R	1mm REF
Х	0.1mm +/-0.1mm

Т

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

General Information	
Series	T495
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR
Features	Low ESR
RoHS	Yes
Termination	Tin
AEC-Q200	No
Component Weight	446.84 mg
Shelf Life	156 Weeks
MSL	1

Specifications	
Capacitance	470 uF
Capacitance Tolerance	10%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	12% 120Hz 25C
Failure Rate	N/A
Resistance	125 mOhms (100kHz 25C)
Ripple Current	1095 mA (rms, 100kHz 25C), 985.5 mA (rms, 85C), 438 mA (rms, 125C)
Leakage Current	29.6 uA (5min 25°C)

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.